NSN 5961-00-246-0583

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View Online at https://aerobasegroup.com/nsn/5961-00-246-0583 **Inclosure Material:** Metal **Overall Length:** 0.750 inches **Overall Diameter:** 0.844 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.875 inches **Thread Size:** 0.312 inches **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 12.0 breakdown voltage, collector-to-base, emitter open **Current Rating Per Characteristic:** 2.50 amperes source cutoff current **Power Rating Per Characteristic:** 20.0 milliwatts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Item must comply with rqmt of desc production standard no. L01085; junction pattern arrangement: npn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 case and 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**

Demilitarization:

No

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